

Description

The ACE2341 is the P-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and Battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

Features

- -20V/-3.3A, $R_{DS(ON)}=45m\Omega @V_{GS}=-4.5V$
- -20V/-2.8A, $R_{DS(ON)}$ = 55m Ω @ V_{GS} =-2.5V
- -20V/-2.3A, $R_{DS(ON)}$ = 65m Ω @ V_{GS} =-1.8V
- Super high density cell design for extremely low R_{DS(ON)}
- Exceptional on-resistance and maximum DC current capability
- SOT-23-3L package design

Application

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

Absolute Maximum Ratings

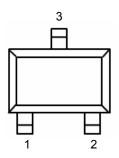
(TA=25°C Unless otherwise noted)

Parameter	Symbol Typical		Unit		
Drain-Source Voltage		V_{DSS}	-20	V	
Gate-Source Voltage	V_{GSS}	±12	V		
Continuous Drain Current (T _J =150°ℂ)	T _A =25°℃	I _D	-4.0	Α	
	T _A =70°C	'D	-2.8		
Pulsed Drain Current		I _{DM}	-12	Α	
Continuous Source Current (Diode Conduction)		I _S	-1.0	Α	
Power Dissipation	T _A =25°℃	P_{D}	1.25	W	
	T _A =70°C	I D	0.8		
Operating Junction Temperature		TJ	-55/150	$^{\circ}\mathbb{C}$	
Storage Temperature Range		T _{STG}	-55/150	$^{\circ}\!\mathbb{C}$	
Thermal Resistance-Junction to Ambient		$R_{\theta JA}$	140	°C/W	

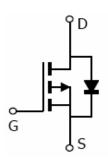


Packaging Type

SOT-23-3

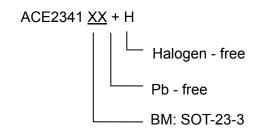


Pin	Description		
1	Gate		
2	Source		
3	Drain		



Ordering information

Selection Guide





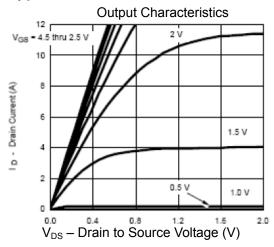
Electrical Characteristics

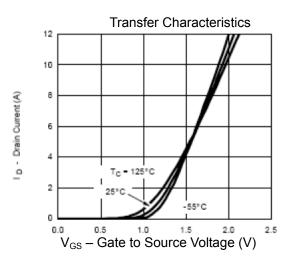
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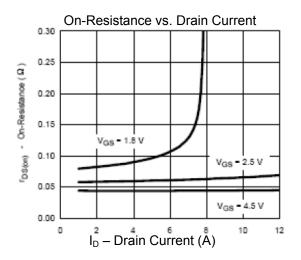
(TA=25℃, Unless otherwise noted)							
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} =0V, I_D =-250uA	-20			V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-0.35		-0.9	v	
Gate Leakage Current	I_{GSS}	V_{DS} =0.V, V_{GS} =±12V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-20V, V_{GS} =0V			-1	uA	
		V_{DS} =-20V, V_{GS} =0V T_J =55°C			-10	uA	
On-State Drain Current	I _{D(ON)}	$V_{DS} \leq -5V$, $V_{GS} = -4.5V$	-6			Α	
Drain-Source On-Resistance	R _{DS(ON)}	V_{GS} =-4.5V, I_{D} =-3.3A		0.036	0.045	Ω	
		V_{GS} =-2.5V, I_{D} =-2.8A		0.045	0.055		
		V_{GS} =-1.8V, I_{D} =-2.3A		0.055	0.065		
Forward Transconductance	Gfs	V_{DS} =-5.0V, I_{D} =-3.3A		3		S	
Diode Forward Voltage	V_{SD}	I _S =-1.6A, V _{GS} =0V		-0.8	-1.2	V	
Dynamic							
Total Gate Charge	Q_{g}	\\ - 6\\ \\ - 4 5\\		8	13		
Gate-Source Charge	Q_gs	V_{DS} =-6V, V_{GS} =-4.5V, I_{D} =-3.3A		1.2		nC	
Gate-Drain Charge	Q_{gd}	I _D ≡-3.3A		2.2			
Input Capacitance	C _{iss}	\\ - 6\\ \\ -0\\		700			
Output Capacitance	Coss	V_{DS} =-6V, V_{GS} =0V, f=1MHz		160		pF	
Reverse Transfer Capacitance	C_{rss}	1=1101112		120			
Turn-On Time	†	V_{DD} =-6V, R_L =6 Ω I_D =-1.0A, V_{GEN} =-4.5V R_G =6 Ω		15	25		
Turn-On Time	t _r			35	55		
Turn-Off Time	t _{d(off)}			60	90	ns	
	t _f	NG-077		40	60		

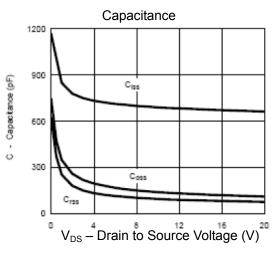


Typical Characteristics



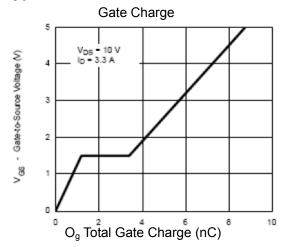


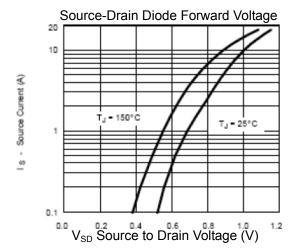


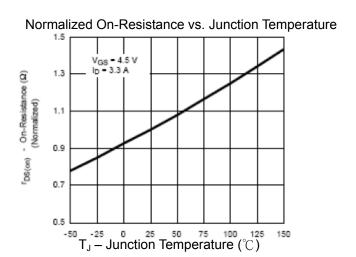


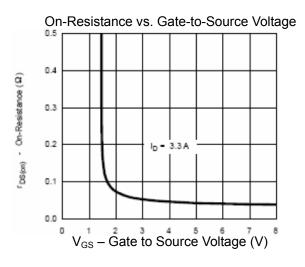


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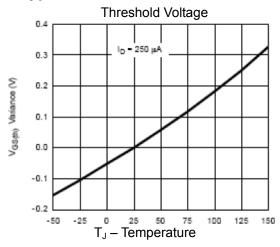


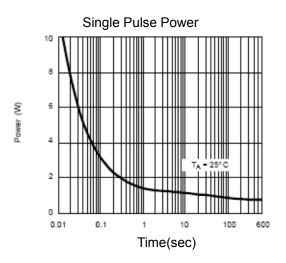


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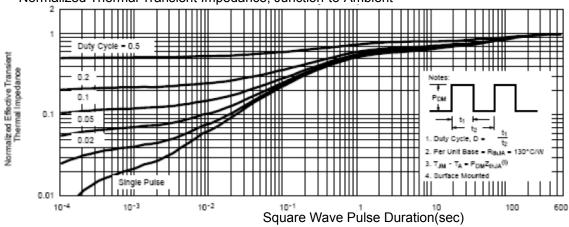


Typical Characteristics





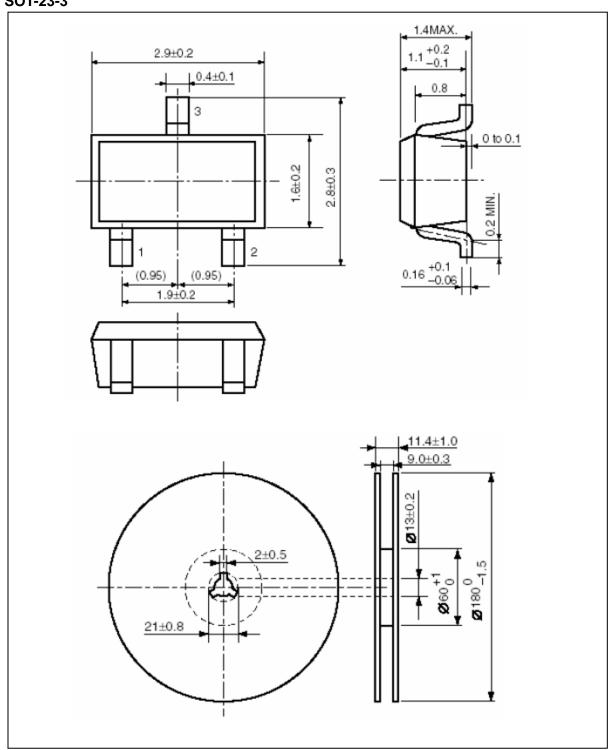






Packing Information

SOT-23-3





Notes

ACE does not assume any responsibility for use as critical components in life support devices or systems without the express written approval of the president and general counsel of ACE Electronics Co., LTD. As sued herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and shoes failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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